NSN 5962-01-379-4396

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View Online at https://aerobasegroup.com/nsn/5962-01-379-4396
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Next asseb: 134360 used on: 134180
Features Provided:
Bipolar and programmed and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Source code listing i/o decode
Voltage Rating And Type Per Characteristic:
-1.5 volts absolute input and 12.0 volts absolute input
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
20 printed circuit
Specification Data:
8134938510/50403bra government specification
Departure From Cited Designator:
Programmed per: Is 134256-01
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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